

JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY: KAKINADA KAKINADA – 533 003, Andhra Pradesh, India DEPARTMENT OF ELECTRONICS AND COMMUNICATION ENGINEERING

| II Year - I Semester | | L | T | P | C |
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| ELECTRONIC DEVICES AND CIRCUITS | | | | | |

Course Objectives:

The main objectives of this course are

- To learn and understand the basic concepts of semiconductor physics.
- Study the physical phenomena such as conduction, transport mechanism and electrical characteristics of different diodes.
- To learn and understandthe application of diodes as rectifiers with their operation and characteristics with and without filters are discussed.
- Acquire knowledge about the principle of working and operation of Bipolar Junction Transistor and Field Effect Transistor and their characteristics.
- To learn and understandthe purpose of transistor biasing and its significance.
- Small signal equivalent circuit analysis of BJT and FET transistor amplifiers and compare differentconfigurations.

UNIT-I:Review of Semi Conductor Physics: Hall effect, continuity equation, law of junction, Fermi Dirac function, Fermi level in intrinsic and extrinsic Semiconductors

Junction Diode Characteristics : energy band diagram of PN junction Diode, Open circuited pn junction, Biased pn junction, pn junction diode, current components in PN junction Diode, diode equation, V-I Characteristics, temperature dependence on V-I characteristics, Diode resistance, Diode capacitance.

UNIT-II:

Special Semiconductor Devices: Zener Diode, Breakdown mechanisms, Zener diode applications, LED, Varactor Diode, Photodiode, Tunnel Diode, UJT, PN-PN Diode, SCR. Construction, operation and V-I characteristics.

Rectifiers and Filters: Basic Rectifier setup, half wave rectifier, full wave rectifier, bridge rectifier, derivations of characteristics of rectifiers, rectifier circuits-operation, input and output waveforms, Filters, Inductor filter(Series inductor), Capacitor filter(Stunt inductor), π -Filter, comparison of various filter circuits in terms of ripple factors.

UNIT-III: Transistor Characteristics:

BJT: Junction transistor, transistor current components, transistor equation, transistor configurations, transistor as an amplifier, characteristics of transistor in Common Base, Common Emitter and Common Collector configurations, Ebers-Moll model of a transistor, punch through/reach through, Photo transistor, typical transistor junction voltage values.

FET: FET types, construction, operation, characteristics μ , g_m , r_d parameters, MOSFET-types, construction, operation, characteristics, comparison between JFET and MOSFET.



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UNIT- IV: Transistor Biasing and Thermal Stabilization: Need for biasing, operating point, load line analysis, BJT biasing- methods, basic stability, fixed bias, collector to base bias, self bias, Stabilization against variations in V_{BE} , Ic, and β , Stability factors, (S,S',S'), Bias compensation, Thermal runaway, Thermalstability.

FET Biasing- methods and stabilization.

UNIT- V: Small Signal Low Frequency Transistor Amplifier Models:

BJT: Two port network, Transistor hybrid model, determination of h-parameters, conversion of h-parameters, generalized analysis of transistor amplifier model using h-parameters, Analysis of CB, CE and CC amplifiers using exact and approximate analysis, Comparison of transistor amplifiers.

FET: Generalized analysis of small signal model, Analysis of CG, CS and CD amplifiers, comparison of FETamplifiers.

Text Books:

- 1. Electronic Devices and Circuits- J. Millman, C. Halkias, Tata Mc-Graw Hill, SecondEdition, 2007
- 2. Electronic Devices and Circuits-K. Lal Kishore, BS Publications, FourthEdition, 2016.
- 3.Electronics devices & circuit theory- Robert L.Boylestad and Loui Nashelsky, Pearson/Prentice hall, tenth edition, 2009

References:

- 1. Integrated Electronics-J. Millman, C. Halkias, Tata Mc-Graw Hill, SecondEdition, 2009
- 2. Electronic Devices and Integrated Circuits B.P. Singh, Rekha, Pearson publications,
- 3.Electronic Devices and Circuits-Salivahanan, Kumar, Vallavaraj, Tata Mc-Graw Hill, 4thEdition,2008.

Course Outcomes:

At the end of this course the student will be able to

- Apply the basic concepts of semiconductor physics.
- Understand the formation of p-n junction and how it can be used as a p-n junction as diode in different modes of operation.
- Know the construction, working principle of rectifiers with and without filters with relevant expressions and necessary comparisons.
- Understand the construction, principle of operation of transistors, BJT and FET withtheir V-I characteristics in different configurations.
- Know the need of transistor biasing, various biasing techniques for BJT and FET and stabilization concepts with necessary expressions.
- Perform the analysis of small signal low frequency transistor amplifier circuits using BJT and FET in different configurations.